



Features

- Avalanche Transistor
- 60A Peak Avalanche Current (Pulse width = 20ns)
- BV_{CES} > 260V (415) & 320V (417)
- BV_{CEO} > 100V
- Specifically designed for Avalanche mode operation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Description

The FMMT415/417 are NPN silicon planar bipolar transistors designed for operating in avalanche mode. Tight process control and low inductance packaging combine to produce high-current pulses with fast edges.



Top View

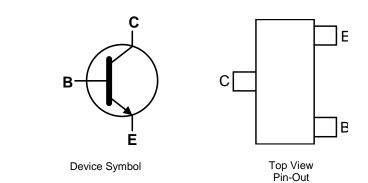
NPN AVALANCHE TRANSISTOR IN SOT23

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 3
- Weight: 0.008 grams (Approximate)

Applications

- Laser Diode Drivers for Ranging and Measurement (LIDAR)
- Radar Systems
- Fast Edge Switch Generator
- High Speed Pulse Generators



Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT415TD	AEC-Q101	415	7	8	500
FMMT417TD	AEC-Q101	417	7	8	500

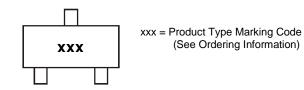
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	FMMT415	FMMT417	Unit
Collector-Base Voltage	V _{CBO}	260	320	V
Collector-Emitter Voltage	V _{CES}	260	320	V
Collector-Emitter Voltage	V _{CEO}	100	100	V
Emitter-Base Voltage	V _{EBO}	6		V
Continuous Collector Current	Ι _C	500		mA
Peak Collector Current (Pulse Width = 20ns)	I _{CM}	60		A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	500	mW	
Thermal Resistance, Junction to Ambient	(Note 5)	R _{0JA}	250	°C/W	
Thermal Resistance, Junction to Lead	(Note 6)	R _{θJL}	197	°C/W	
Operating and Storage Temperature Range		TJ. TSTG	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

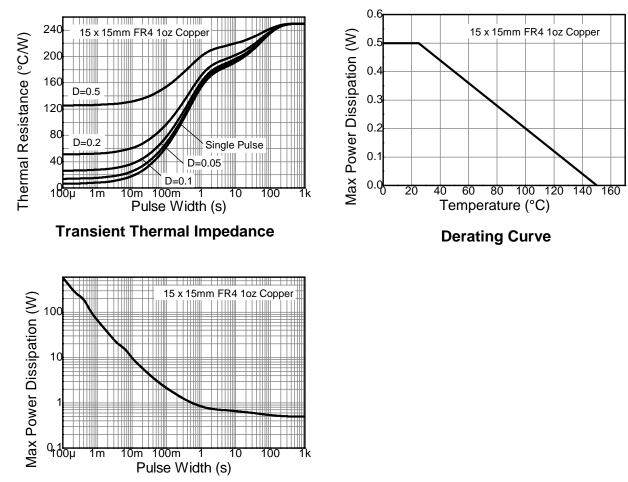
Notes: 5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



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Thermal Characteristics and Derating Information



Pulse Power Dissipation



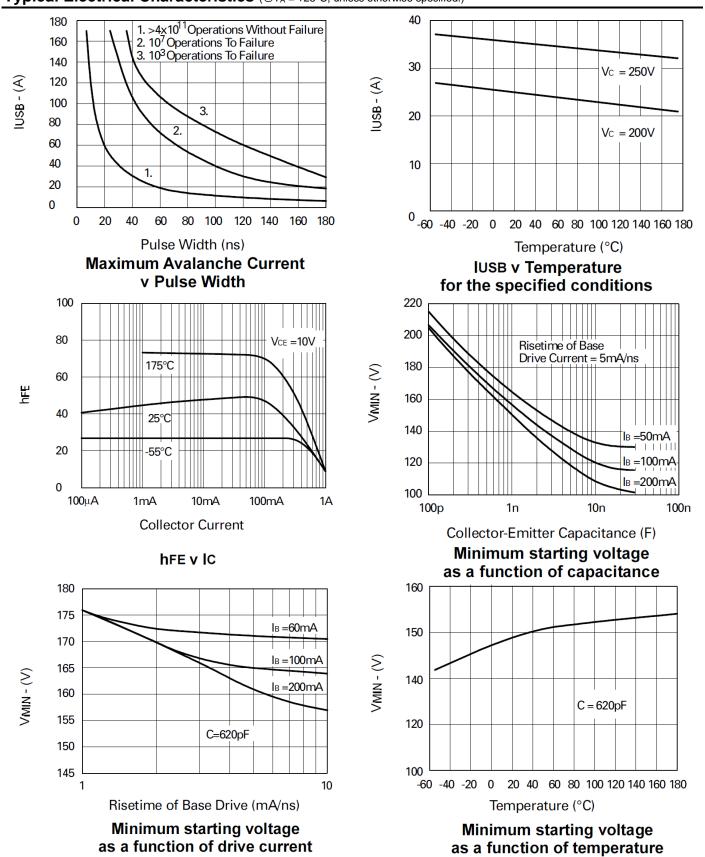
FMMT415 FMMT417

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
Collector-Emitter Breakdown Voltage	FMMT415	BV _{CES}	260			V	$I_C = 1mA$ $T_J = -55 \text{ to } +150^{\circ}\text{C}$
	FMMT417		320	_	_		I _C = 1mA
Collector-Emitter Breakdown Voltage (Not	e 8)	BV _{CEO}	100	_	_	V	I _C = 100μA
Emitter-Base Breakdown Voltage		BV _{EBO}	6	_	_	V	I _E = 100μA
Collector Cutoff Current		I _{CBO}	_	_	100 10	nA μA	V _{CB} = 180V V _{CB} = 180V, T _J = +100°C
Emitter Cutoff Current		I _{EBO}	_	_	100	nA	$V_{EB} = 4V$
Static Forward Current Transfer Ratio (Note 8)		h _{FE}	25	_	_	—	$I_{C} = 10 \text{mA}, V_{CE} = 10 \text{V}$
Collector-Emitter Saturation Voltage (Note 8)		V _{CE(sat)}	_	_	500	mV	$I_{\rm C}$ = 10mA, $I_{\rm B}$ = 1mA
Base-Emitter Saturation Voltage (Note 8)		V _{BE(sat)}	_	_	900	mV	$I_{\rm C}$ = 10mA, $I_{\rm B}$ = 1mA
Pulsed Current in Second Breakdown		I _{USB}	_	25 35		A A	$V_{C} = 200V, C_{CE} = 620pF$ $V_{C} = 250V, C_{CE} = 620pF$
Collector-Emitter Inductance		Lce	_	2.5	_	nH	Standard SOT23 leads
Output Capacitance		Cobo	_	_	8	pF	$V_{CB} = 20V, I_E = 0$ f = 100MHz
Transition Frequency		f⊤	40	_	_	MHz	$V_{CE} = 20V, I_C = 10mA,$ f = 20MHz

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.





Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

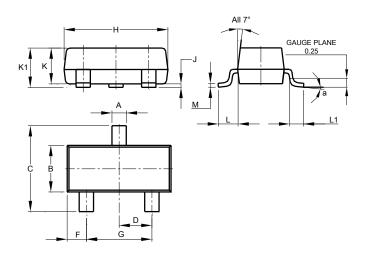
FMMT415 - FMMT417 Datasheet Number: DS33084 Rev. 6 - 2 November 2015 © Diodes Incorporated



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Package Outline Dimensions

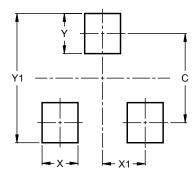
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All	All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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